



40V N-Channel Enhancement Mode MOSFET

Voltage

40 V

Current

61 A

Features

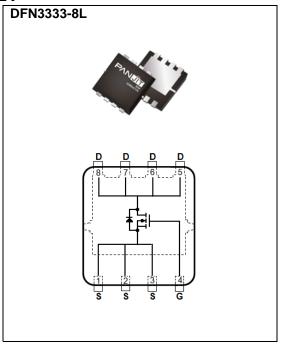
- RDS(ON), VGS@10V, ID@15A<6.3m Ω
- R_{DS(ON)}, V_{GS}@7V, I_D@10A<7.7mΩ
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETE | SYMBOL | LIMIT | UNITS | | |
|---|-----------------------|----------------------------------|---------|-------|--|
| Drain-Source Voltage | | V _{DS} | 40 | V | |
| Gate-Source Voltage | | V _{GS} | ±20 | \ \ \ | |
| Continuous Drain Current(Note 3) | T _C =25°C | | 61 | A | |
| | T _C =100°C | l _D | 43 | | |
| Pulsed Drain Current(Note 1) | T _C =25°C | I _{DM} | 244 | | |
| Power Dissipation | T _C =25°C | Po | 42 | 147 | |
| | T _C =100°C | | 21 | W | |
| Continuous Drain Current(Note 4) | T _A =25°C | | 15 | | |
| | T _A =70°C | I _D | 12.4 | _ A | |
| Power Dissipation | T _A =25°C | 5 | 2.5 | W | |
| | T _A =70°C | Po | 1.8 | | |
| Single Pulse Avalanche Energy ^(Note 5) | | Eas | 85 | mJ | |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~175 | °C | |
| Thermal Resistance(Note 4) | Junction to Case | R _{θJC} | 3.6 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 60 | | |





Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | | |
|----------------------------------|---------------------|--|------|------|------|-------|--|--|
| Static | | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 40 | - | - | V | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =50uA | 2 | 2.8 | 3.5 | | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =15A | - | 5 | 6.3 | mΩ | | |
| | | V _{GS} =7V, I _D =10A | - | 5.9 | 7.7 | | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =40V, V _{GS} =0V | - | - | 1 | uA | | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA | | |
| Dynamic ^(Note 6) | | | | | | • | | |
| Total Gate Charge | Q_g | V _{DS} =32V, I _D =15A, V _{GS} =10V ^(Note 2,3) | - | 23 | - | nC | | |
| Gate-Source Charge | Qgs | | - | 5 | - | | | |
| Gate-Drain Charge | Q_{gd} | | - | 6 | - | | | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1MHZ | - | 1283 | - | pF | | |
| Output Capacitance | Coss | | - | 252 | - | | | |
| Reverse Transfer Capacitance | Crss | | - | 45 | - | | | |
| Gate resistance | Rg | f=1MHZ | - | 0.8 | - | Ω | | |
| Turn-On Delay Time | td _(on) | V_{DS} =32V, I_{D} =15A, V_{GS} =10V, R_{G} =3 Ω (Note 2,3) | - | 17 | - | ns | | |
| Turn-On Rise Time | tr | | - | 79 | - | | | |
| Turn-Off Delay Time | td(off) | | - | 37 | - | | | |
| Turn-Off Fall Time | tf | | - | 23 | - | | | |
| Drain-Source Diode | | | _ | | | _ | | |
| Diode Forward Current | Is | T _C =25°C | - | - | 61 | A | | |
| Pulsed Diode Forward Current | I _{SM} | | - | - | 244 | | | |
| Diode Forward Voltage | V _{SD} | I _S =20A, V _{GS} =0V | - | 0.85 | 1.3 | V | | |
| Reverse Recovery Time | Trr | V _{GS} =0V, I _S =20A | - | 43 | - | ns | | |
| Reverse Recovery Charge | Qrr | dls/dt=100A/us | - | 34 | - | nC | | |

NOTES:

- 1. Pulse width<100us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an R_{eJC}=3.6°C/W.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=18A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25°C.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

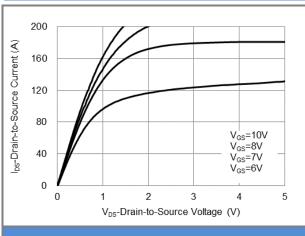


Fig.1 On-Region Characteristics

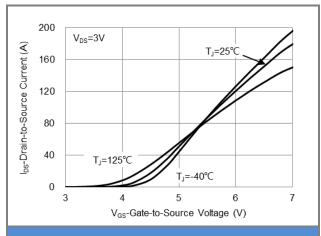


Fig.2 Transfer Characteristics

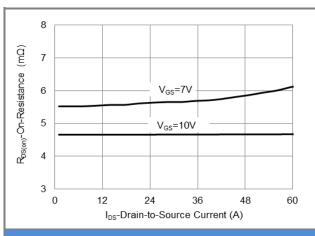


Fig.3 On-Resistance vs. Drain Current

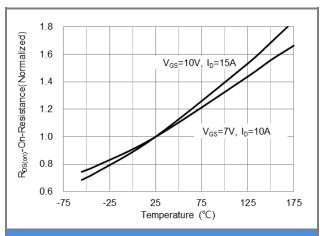
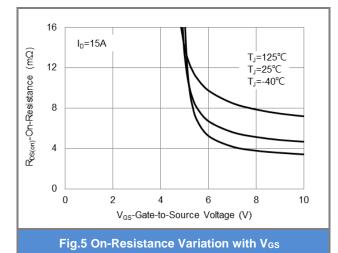


Fig.4 On-Resistance vs. Junction temperature



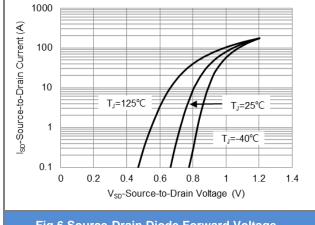


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

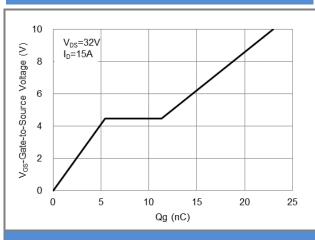


Fig.7 Gate-Charge Characteristics

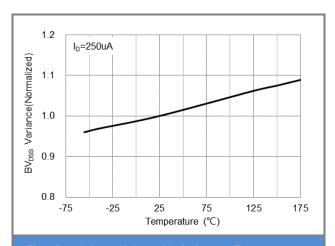


Fig.8 Breakdown Voltage Variation vs. Temperature

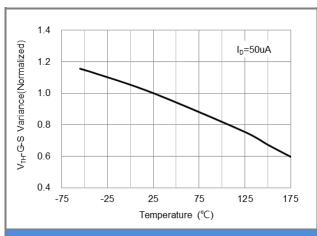


Fig.9 Threshold Voltage Variation with Temperature

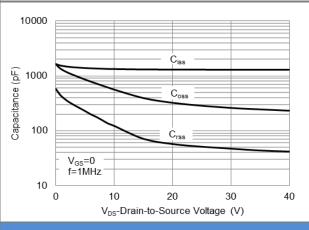
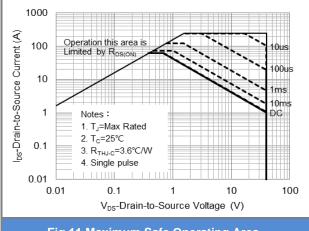


Fig.10 Capacitance vs. Drain-Source Voltage





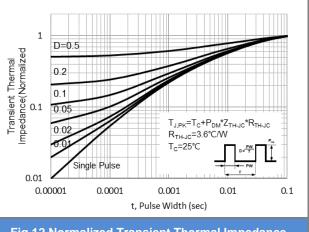


Fig.12 Normalized Transient Thermal Impedance

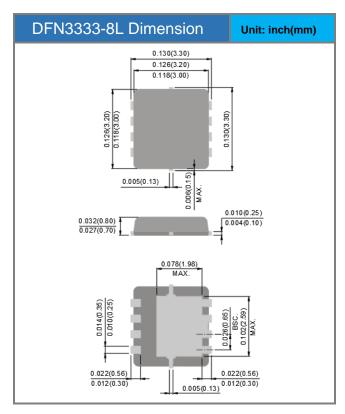


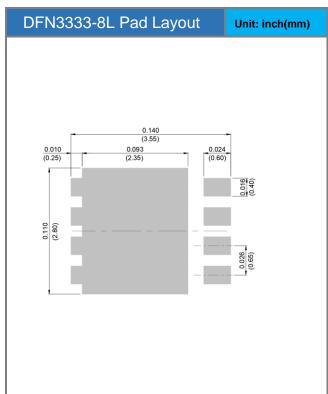


Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|-------------------|---------|--------------------------------|
| PJQ4546VP-AU_R2_002A1 | DFN3333-8L | 5K pcs / 13" reel | 546V | Halogen free RoHS compliant |

Packaging Information & Mounting Pad Layout









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